

GC2X8MPS12-247

1200V 15A SiC Schottky MPS™ Diode



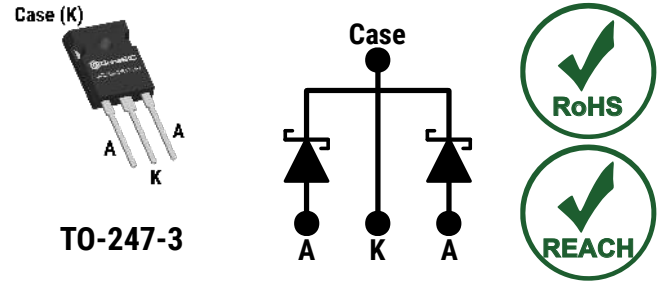
Silicon Carbide Schottky Diode

V _{RRM}	=	1200 V
I _F (T _C = 135°C)	=	30 A *
Q _C	=	80 nC *

Features

- Low V_F for High Temperature Operation
- Enhanced Surge and Avalanche Robustness
- Superior Figure of Merit Q_C/I_F
- Low Thermal Resistance
- Low Reverse Leakage Current
- Temperature Independent Fast Switching
- Positive Temperature Coefficient of V_F
- High dV/dt Ruggedness

Package



Advantages

- Improved System Efficiency
- High System Reliability
- Optimal Price Performance
- Reduced Cooling Requirements
- Increased System Power Density
- Zero Reverse Recovery Current
- Easy to Parallel without Thermal Runaway
- Enables Extremely Fast Switching

Applications

- Power Factor Correction (PFC)
- Solar Inverters
- Battery Chargers
- High Frequency Converters
- Switched Mode Power Supply (SMPS)
- AC/DC Power Supplies
- Anti-Parallel / Free-Wheeling Diode
- LED and HID Lighting

Absolute Maximum Ratings (At T_C = 25°C Unless Otherwise Stated)

Parameter	Symbol	Conditions	Values	Unit	Note
Repetitive Peak Reverse Voltage (Per Leg)	V _{RRM}		1200	V	
Continuous Forward Current (Per Leg / Per Device)	I _F	T _C = 100°C, D = 1	21 / 42	A	Fig. 4
		T _C = 135°C, D = 1	15 / 30		
		T _C = 162°C, D = 1	7.5 / 15		
Non-Repetitive Peak Forward Surge Current, Half Sine Wave (Per Leg)	I _{F,SM}	T _C = 25°C, t _p = 10 ms	75	A	
		T _C = 150°C, t _p = 10 ms	60		
Repetitive Peak Forward Surge Current, Half Sine Wave (Per Leg)	I _{F,RM}	T _C = 25°C, t _p = 10 ms	45	A	
		T _C = 150°C, t _p = 10 ms	32		
Non-Repetitive Peak Forward Surge Current (Per Leg)	I _{F,MAX}	T _C = 25°C, t _p = 10 μs	375	A	
i ² t Value (Per Leg)	∫i ² dt	T _C = 25°C, t _p = 10 ms	28	A ² s	
Non-Repetitive Avalanche Energy (Per Leg)	E _{AS}	L = 4.8 mH, I _{AS} = 7.5 A	135	mJ	
Diode Ruggedness (Per Leg)	dV/dt	V _R = 0 ~ 960 V	200	V/ns	
Power Dissipation (Per Leg / Per Device)	P _{TOT}	T _C = 25°C	166 / 332	W	Fig. 3
Operating and Storage Temperature	T _j , T _{stg}		-55 to 175	°C	

* Per Device

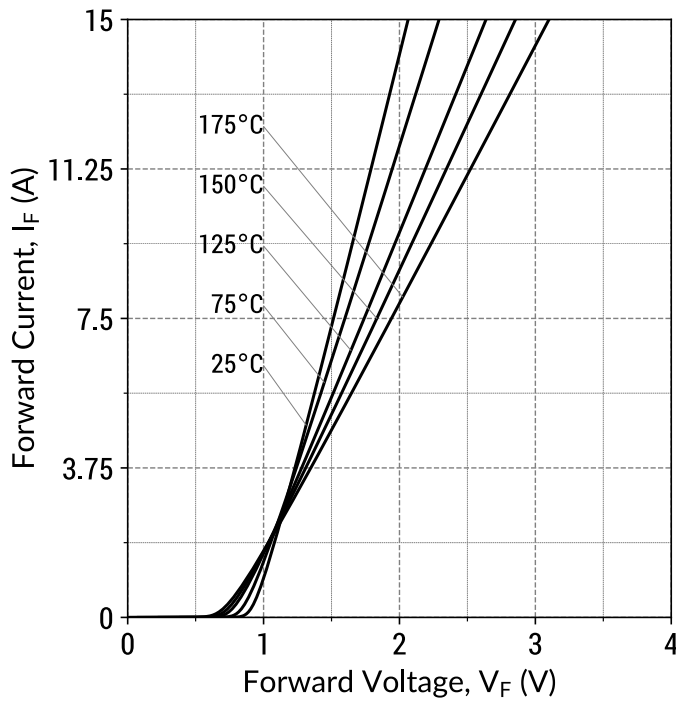
Electrical Characteristics (Per Leg)

Parameter	Symbol	Conditions	Values			Unit	Note
			Min.	Typ.	Max.		
Diode Forward Voltage	V_F	$I_F = 7.5 \text{ A}, T_j = 25^\circ\text{C}$ $I_F = 7.5 \text{ A}, T_j = 175^\circ\text{C}$		1.5 1.9	1.8	V	Fig. 1
Reverse Current	I_R	$V_R = 1200 \text{ V}, T_j = 25^\circ\text{C}$ $V_R = 1200 \text{ V}, T_j = 175^\circ\text{C}$		1 9	5	μA	Fig. 2
Total Capacitive Charge	Q_C	$I_F \leq I_{F,MAX}$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$		28 40		nC	Fig. 7
			$V_R = 400 \text{ V}$ $V_R = 800 \text{ V}$				
Switching Time	t_s			< 10		ns	
		$V_R = 400 \text{ V}$ $V_R = 800 \text{ V}$					
Total Capacitance	C	$V_R = 1 \text{ V}, f = 1\text{MHz}$ $V_R = 800 \text{ V}, f = 1\text{MHz}$		457 27		pF	Fig. 6

Thermal/Package Characteristics

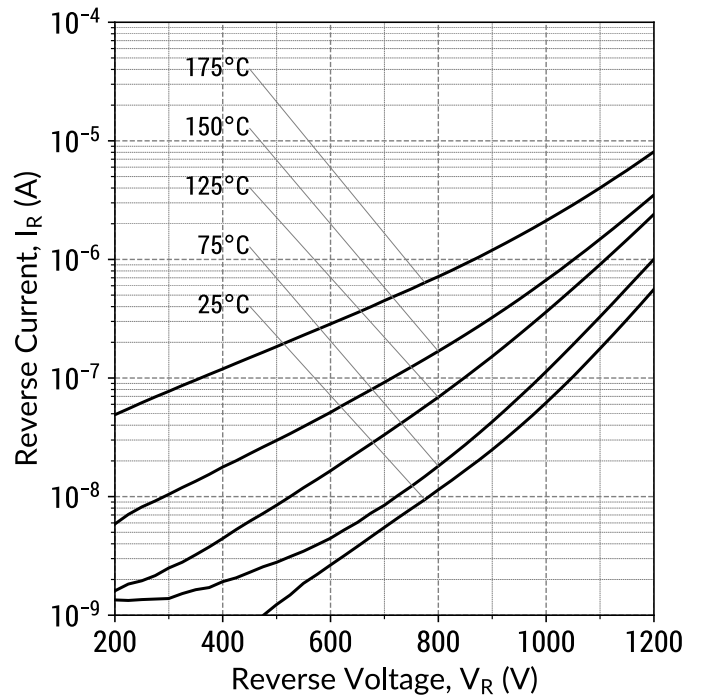
Parameter	Symbol	Conditions	Values			Unit	Note
			Min.	Typ.	Max.		
Thermal Resistance, Junction - Case (Per Leg)	R_{thJC}			0.9		$^\circ\text{C}/\text{W}$	Fig. 9
Weight	W_T			6.1		g	
Mounting Torque	T_M	Screws to Heatsink			1.1	Nm	

Figure 1: Typical Forward Characteristics (Per Leg)



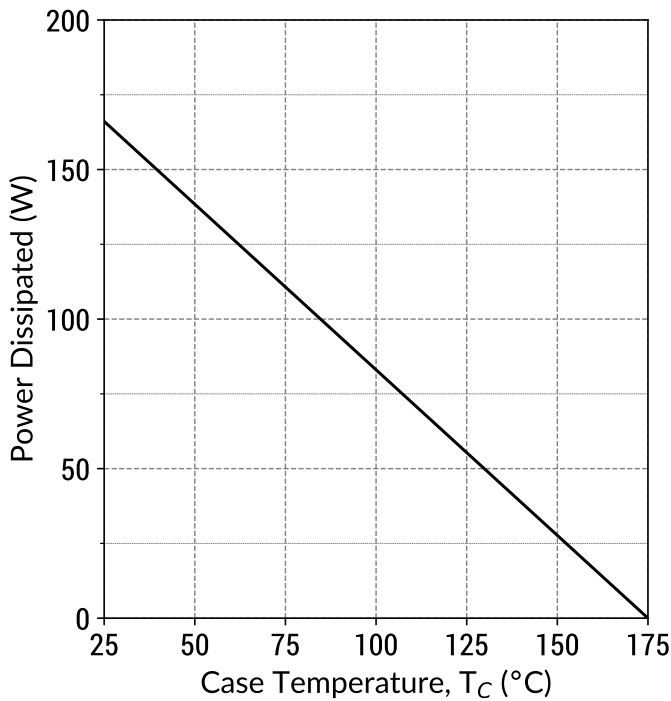
$$I_F = f(V_F, T_j); t_p = 250 \mu s$$

Figure 2: Typical Reverse Characteristics (Per Leg)



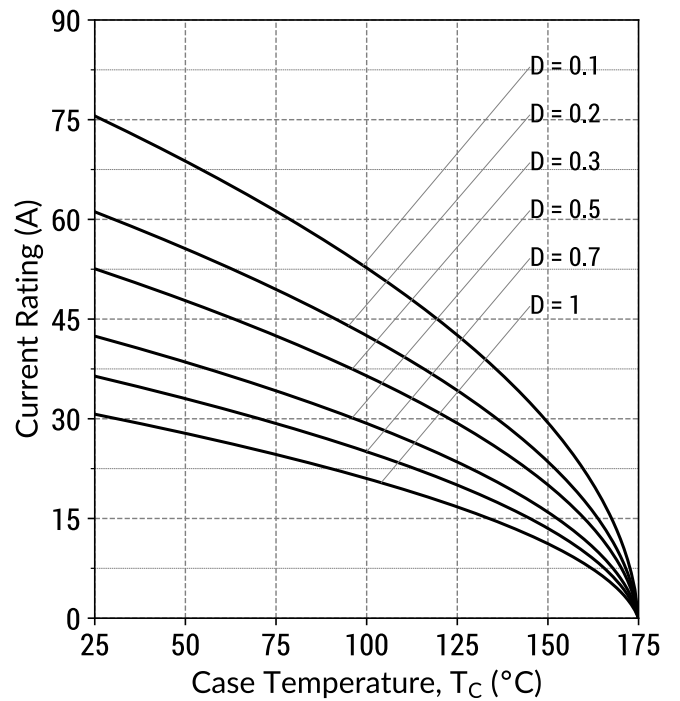
$$I_R = f(V_R, T_j)$$

Figure 3: Power Derating Curves (Per Leg)



$$P_{TOT} = f(T_C); T_j = 175^\circ C$$

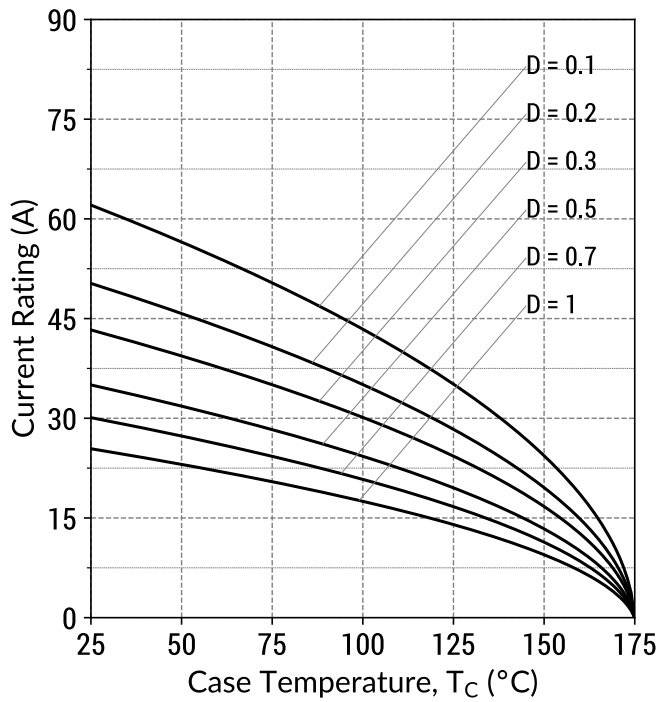
Figure 4: Current Derating Curves (Typical V_F) (Per Leg)



$$I_F = f(T_C); D = t_p/T; T_j \leq 175^\circ C; f_{sw} > 10kHz$$

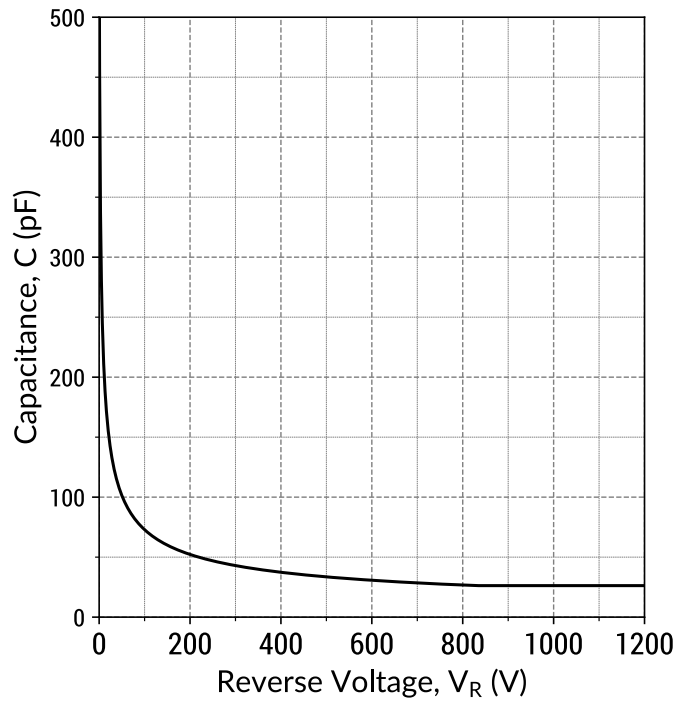


Figure 5: Current Derating Curves (Maximum V_F) (Per Leg)



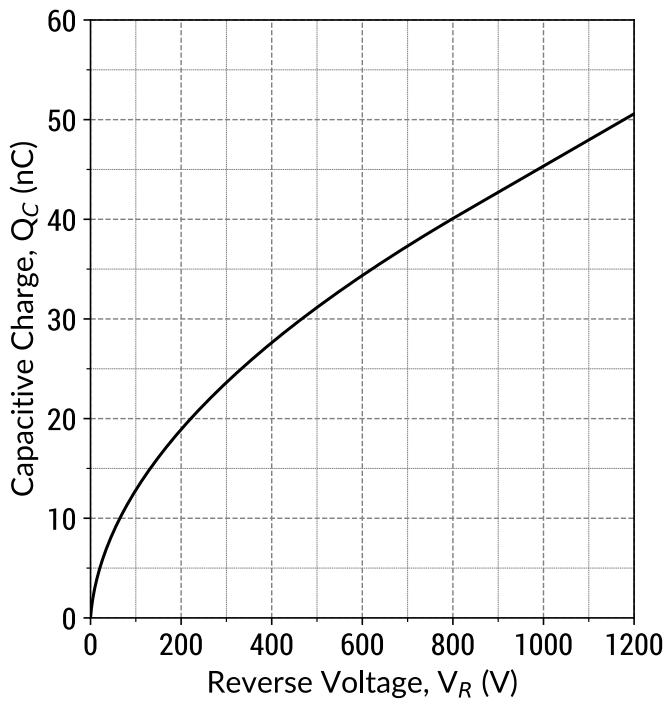
$I_F = f(T_C)$; $D = t_p/T$; $T_j \leq 175^\circ\text{C}$; $f_{sw} > 10\text{kHz}$

Figure 6: Typical Junction Capacitance vs Reverse Voltage Characteristics (Per Leg)



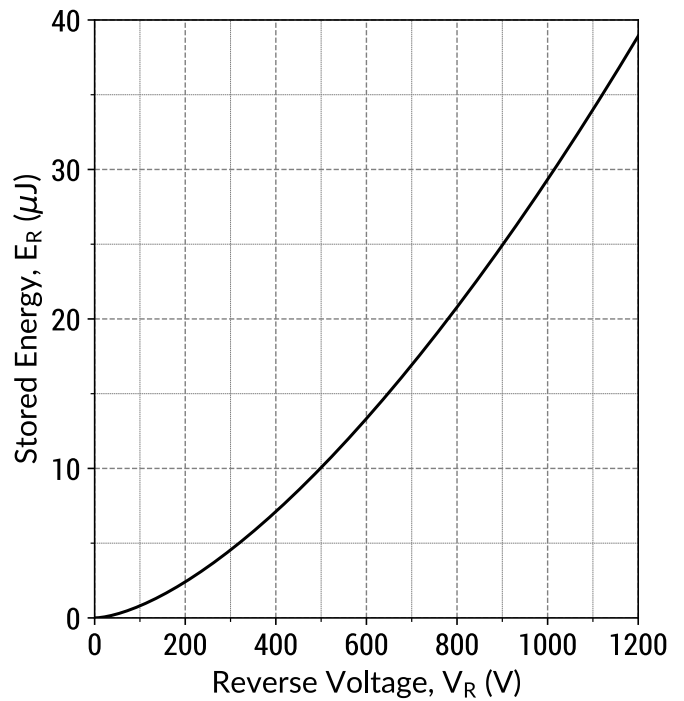
$C = f(V_R)$; $f = 1\text{MHz}$

Figure 7: Typical Capacitive Charge vs Reverse Voltage Characteristics (Per Leg)



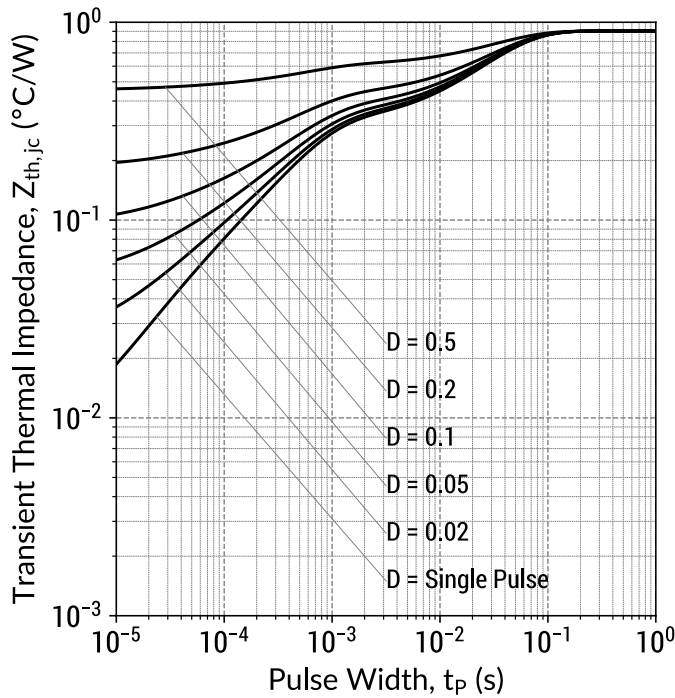
$Q_C = f(V_R)$; $f = 1\text{MHz}$

Figure 8: Typical Capacitive Energy vs Reverse Voltage Characteristics (Per Leg)



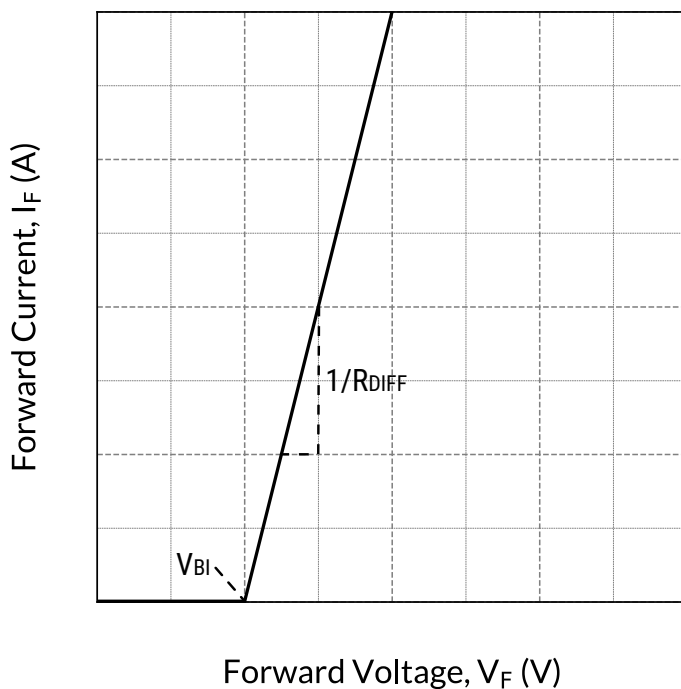
$E_C = f(V_R)$; $f = 1\text{MHz}$

Figure 9: Transient Thermal Impedance (Per Leg)



$$Z_{th,jc} = f(t_p, D); D = t_p/T$$

Figure 10: Forward Curve Model (Per Leg)



$$I_F = f(V_F, T_j)$$

Forward Curve Model Equation:

$$I_F = (V_F - V_{BI})/R_{DIFF} \text{ (A)}$$

Built-In Voltage (V_{BI}):

$$V_{BI}(T_j) = m \times T_j + n \text{ (V)}$$

$$m = -0.00123 \text{ (V/°C)}$$

$$n = 0.995 \text{ (V)}$$

Differential Resistance (R_{DIFF}):

$$R_{DIFF}(T_j) = a \times T_j^2 + b \times T_j + c \text{ (}\Omega\text{)}$$

$$a = 1.59e-06 \text{ (}\Omega\text{/°C}^2\text{)}$$

$$b = 0.000226 \text{ (}\Omega\text{/°C)}$$

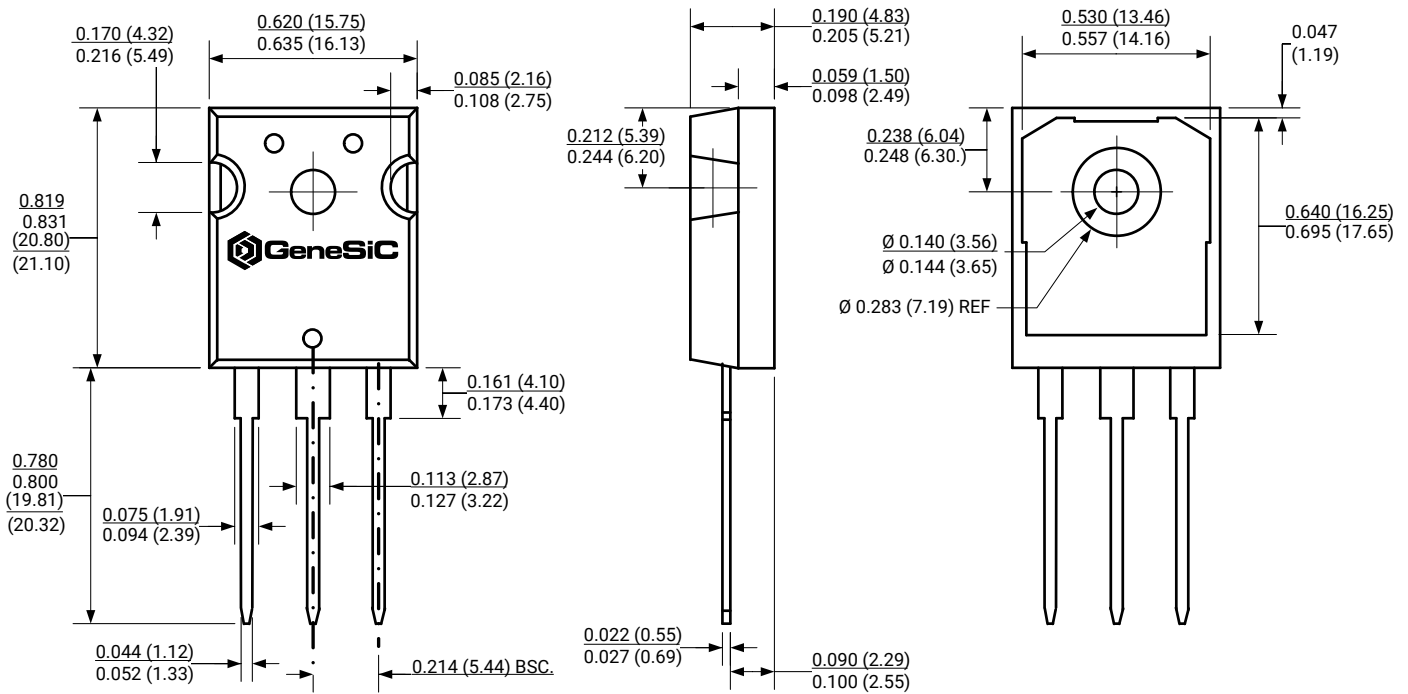
$$c = 0.0669 \text{ (}\Omega\text{)}$$

Forward Power Loss Equation:

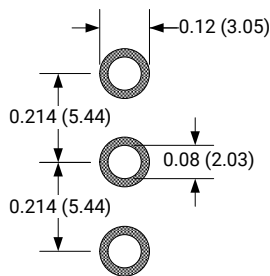
$$P_{LOSS} = V_{BI}(T_j) \times I_{AVG} + R_{DIFF}(T_j) \times I_{RMS}^2$$

Package Dimensions

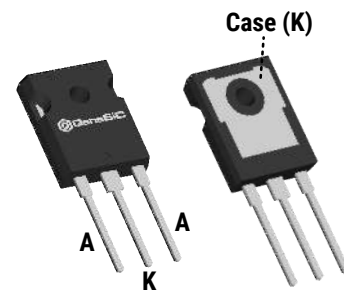
TO-247-3 Package Outline



Recommended Solder Pad Layout



Package View



NOTE

1. CONTROLLED DEIMENSION IS INCH. DIMENSION IN BRACKET IS MILLIMETER.
2. DIMENSIONS DO NOT INCLUDE END FLASH, MOLD FLASH, MATERIAL PROTRUSIONS.

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS 2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863. RoHS Declarations for this product can be obtained from your GeneSiC representative.

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This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.

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- SPICE Models: https://www.genesicsemi.com/sic-schottky-mps/GC2X8MPS12-247/GC2X8MPS12-247_SPICE.zip
- PLECS Models: https://www.genesicsemi.com/sic-schottky-mps/GC2X8MPS12-247/GC2X8MPS12-247_PLECS.zip
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